# Freescale Semiconductor Technical Data

MHL21336 Rev. 4, 1/2005

Will be replaced by MHL21336N in March 2005. There are no form, fit or function changes with this part replacement. N suffix added to part number to indicate transition to lead-free terminations.

# 3G Band RF Linear LDMOS Amplifier

Designed for ultra-linear amplifier applications in 50 ohm systems operating in the 3G frequency band. A silicon FET Class A design provides outstanding linearity and gain. In addition, the excellent group delay and phase linearity characteristics are ideal for digital CDMA modulation systems.

• Third Order Intercept: 45 dBm Typ

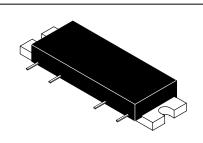
INFORMAT

**3CHIVE** 

- Power Gain: 31 dB Typ (@ f = 2140 MHz)
- Excellent Phase Linearity and Group Delay Characteristics
- Ideal for Feedforward Base Station Applications



2110-2170 MHz 3.0 W, 31 dB RF LINEAR LDMOS AMPLIFIER



CASE 301AP-02, STYLE 1

## **Table 1. Absolute Maximum Ratings** ( $T_C = 25^{\circ}C$ unless otherwise noted)

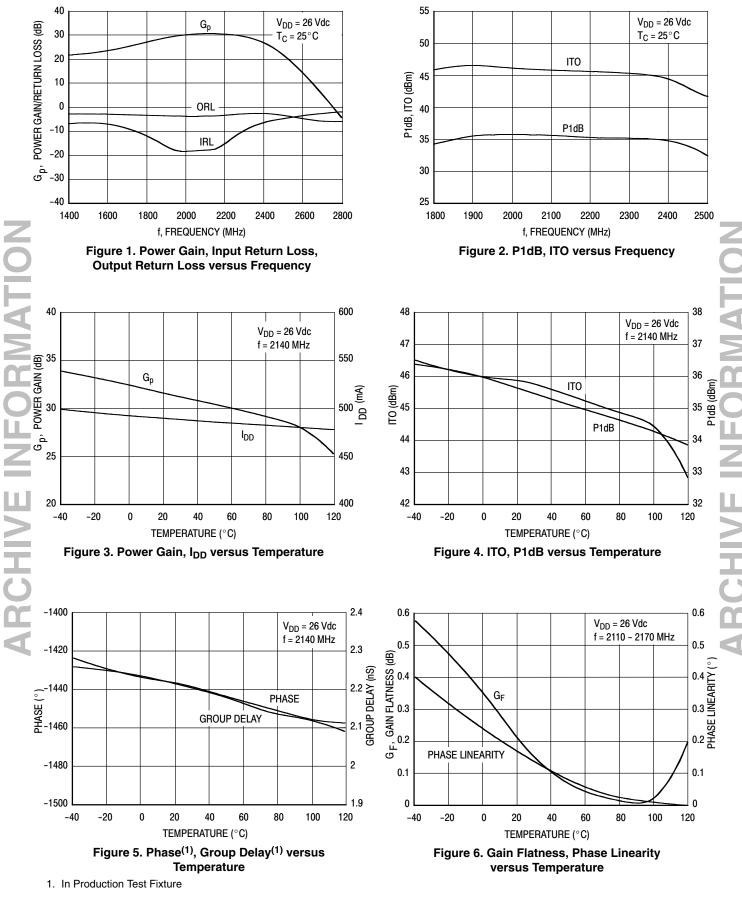
Rating	Symbol	Value	Unit
DC Supply Voltage	V <sub>DD</sub>	30	Vdc
RF Input Power	P <sub>in</sub>	+5	dBm
Storage Temperature Range	T <sub>stg</sub>	- 40 to +100	°C
Operating Case Temperature Range	T <sub>C</sub>	- 20 to +100	°C

**Table 2. Electrical Characteristics** ( $V_{DD}$  = 26 Vdc,  $T_C$  = 25°C; 50  $\Omega$  System)

Characteristic		Symbol	Min	Тур	Max	Unit
Supply Current		I <sub>DD</sub>	—	500	525	mA
Power Gain	(f = 2140 MHz)	Gp	30	31	32	dB
Gain Flatness	(f = 2110 - 2170 MHz)	G <sub>F</sub>	—	0.15	0.4	dB
Power Output @ 1 dB Comp.	(f = 2140 MHz)	P <sub>out</sub> 1 dB	34	35	_	dBm
Input VSWR	(f = 2110 - 2170 MHz)	VSWR <sub>in</sub>	—	1.2:1	1.5:1	
Third Order Intercept (f1 = 2137 MHz, f2 = 2	142 MHz)	ITO	44	45	_	dBm
Noise Figure	(f = 2170 MHz)	NF	—	4.5	5	dB

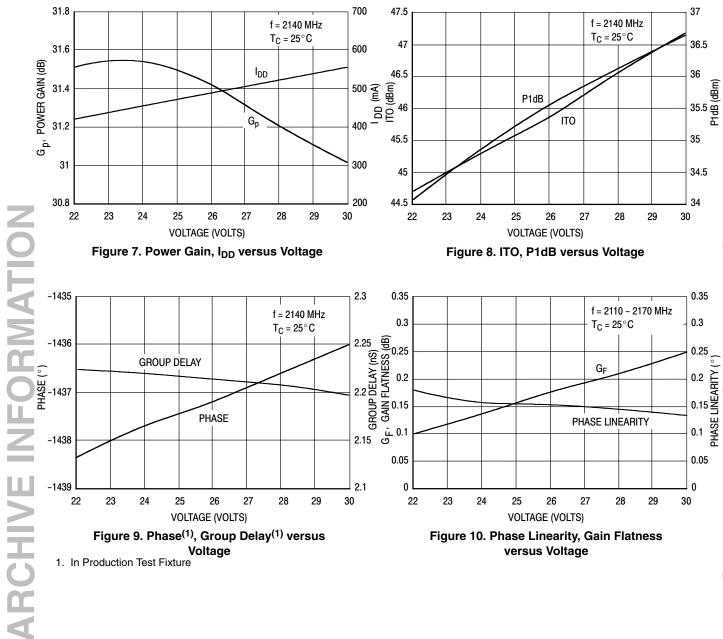


# TYPICAL CHARACTERISTICS



MHL21336

# **TYPICAL CHARACTERISTICS**



MHL21336

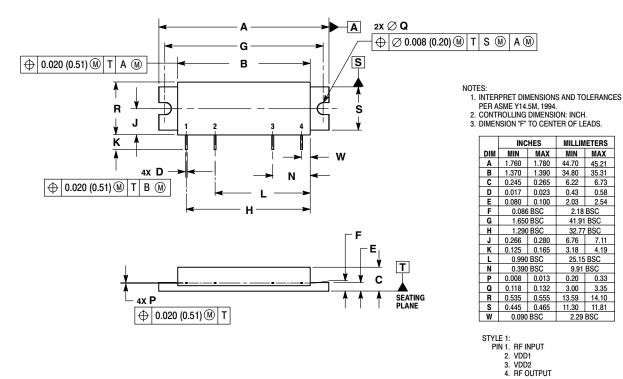
NOTES

# **ARCHIVE INFORMATION**

# NOTES

NOTES

# PACKAGE DIMENSIONS



**CASE 301AP-02 ISSUE C** 

**RF** Device Data

Freescale Semiconductor

MILLIMETERS

0.43 0.58

2.03 2.54

2.18 BSC

41.91 BSC

32.77 BSC

6.76 7.11 3.18 4.19

25.15 BSC

9.91 BSC

2.29 BSC

CASE: GROUND

0.20 0.33 3.00 3.35

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